

**SOP-8 P Channel Enhancement 沟道增强型
MOS Field Effect Transistor 场效应管**

■ Features 特点

Low on-resistance 低导通电阻

$R_{DS(ON)}=13m\Omega(\text{Type})@V_{GS}=-10V$

$R_{DS(ON)}=17.5m\Omega(\text{Type})@V_{GS}=-4.5V$

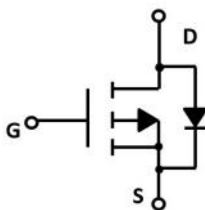
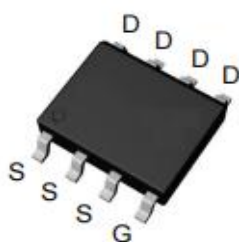
■ Applications 应用

Load Switch 负载开关

DC/DC Power System 电源升压系统

Power Management in LCD TV Inverter 液晶电视电源管理

■ Internal Schematic Diagram 内部结构



■ Absolute Maximum Ratings 最大额定值

Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
Drain-Source Voltage 漏极-源极电压	BV_{DSS}	-40	V
Gate- Source Voltage 栅极-源极电压	V_{GS}	± 20	V
Drain Current (continuous)漏极电流-连续	I_D (at $T_A = 25^\circ\text{C}$)	-12	A
Drain Current (pulsed)漏极电流-脉冲	I_{DM}	-52	A
Total Device Dissipation 总耗散功率	$P_{TOT}(\text{at } T_A = 25^\circ\text{C})$	3	W
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	41	$^\circ\text{C}/\text{W}$
Avalanche Energy Single Pulse 雪崩能量 $V_{DD}=-25V, V_{GS}=-10V, L=0.1mH, I_{AS}=-34A.$	E_{AS}	80	mJ
Junction/Storage Temperature 结温/储存温度	T_J, T_{stg}	-55~150	$^\circ\text{C}$

■ **Electrical Characteristics 电特性**

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位
Drain-Source Breakdown Voltage 漏极-源极击穿电压($I_D = -250\mu\text{A}, V_{GS}=0\text{V}$)	BV_{DSS}	-40	—	—	V
Gate Threshold Voltage 栅极开启电压($I_D = -250\mu\text{A}, V_{GS} = V_{DS}$)	$V_{GS(th)}$	-1	-1.5	-2.2	V
Zero Gate Voltage Drain Current 零栅压漏极电流($V_{GS}=0\text{V}, V_{DS}= -40\text{V}$)	I_{DSS}	—	—	-1	μA
Gate Body Leakage 栅极漏电流($V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$)	I_{GSS}	—	—	± 100	nA
Static Drain-Source On-State Resistance 静态漏源导通电阻($I_D = -10\text{A}, V_{GS} = -10\text{V}$) ($I_D = -5\text{A}, V_{GS} = -4.5\text{V}$)	$R_{DS(ON)}$	—	13 17.5	16 23	$\text{m}\Omega$
Diode Forward Voltage Drop 内附二极管正向压降($I_{SD} = -10\text{A}, V_{GS}=0\text{V}$)	V_{SD}	—	—	-1.2	V
Input Capacitance 输入电容 ($V_{GS}=0\text{V}, V_{DS}= -20\text{V}, f=1\text{MHz}$)	C_{ISS}	—	2525	—	pF
Common Source Output Capacitance 共源输出电容($V_{GS}=0\text{V}, V_{DS}= -20\text{V}, f=1\text{MHz}$)	C_{OSS}	—	190	—	pF
Reverse Transfer Capacitance 反馈电容 ($V_{GS}=0\text{V}, V_{DS}= -20\text{V}, f=1\text{MHz}$)	C_{RSS}	—	172	—	pF
Total Gate Charge 栅极电荷密度 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, V_{GS} = -10\text{V}$)	Q_g	—	35	—	nC
Gate Source Charge 栅源电荷密度 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, V_{GS} = -10\text{V}$)	Q_{gs}	—	5.5	—	nC
Gate Drain Charge 栅漏电荷密度 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, V_{GS} = -10\text{V}$)	Q_{gd}	—	8	—	nC
Turn-ON Delay Time 开启延迟时间 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, R_{GEN}=3\Omega, V_{GS} = -10\text{V}$)	$t_{d(on)}$	—	14.5	—	ns
Turn-ON Rise Time 开启上升时间 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, R_{GEN}=3\Omega, V_{GS} = -10\text{V}$)	t_r	—	20.2	—	ns
Turn-OFF Delay Time 关断延迟时间 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, R_{GEN}=3\Omega, V_{GS} = -10\text{V}$)	$t_{d(off)}$	—	32	—	ns
Turn-OFF Fall Time 关断下降时间 ($V_{DS} = -20\text{V}, I_D = -10\text{A}, R_{GEN}=3\Omega, V_{GS} = -10\text{V}$)	t_f	—	10	—	ns

■ Typical Characteristic Curve 典型特性曲线

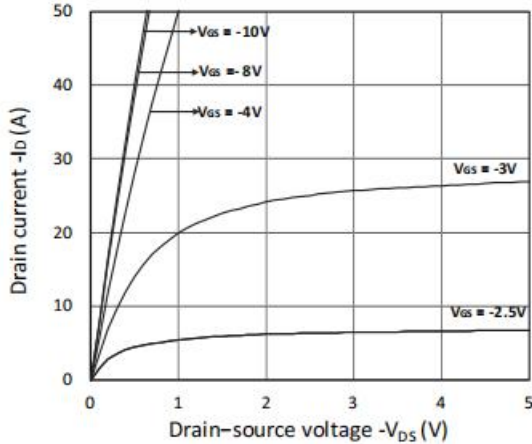


Figure 1: Output Characteristics

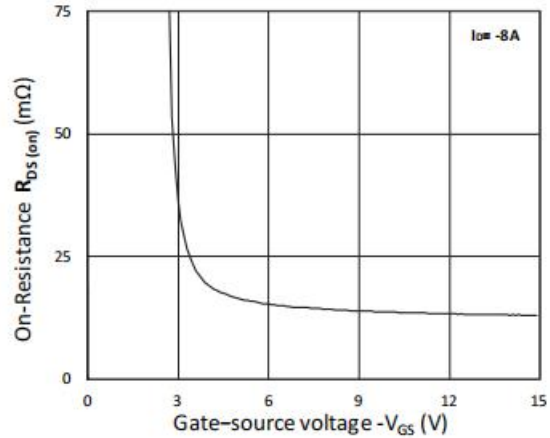


Figure 2: On-Resistance vs. V_{GS}

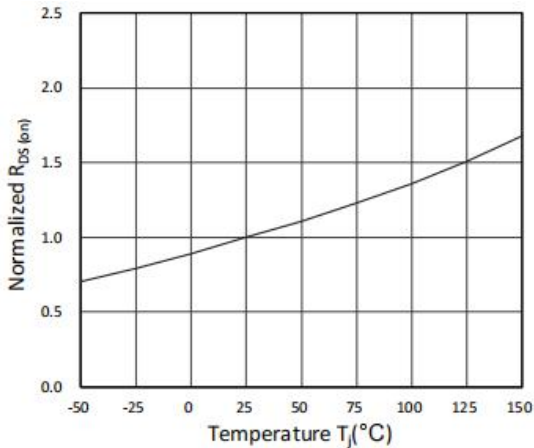


Figure 3: On-Resistance vs. T_J

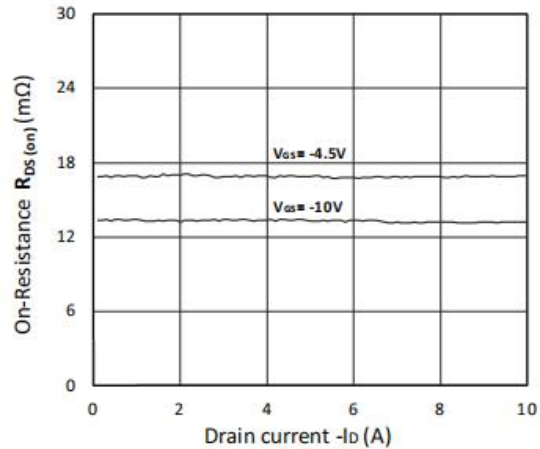


Figure 4: On-Resistance vs. Drain Current

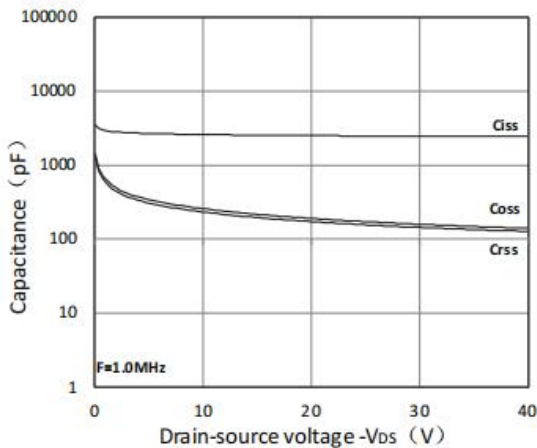


Figure 5: Capacitance Characteristics

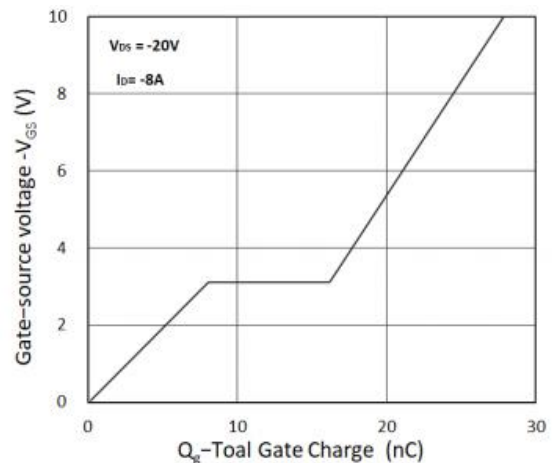


Figure 6: Gate-Charge Characteristics

■ Typical Characteristic Curve 典型特性曲线

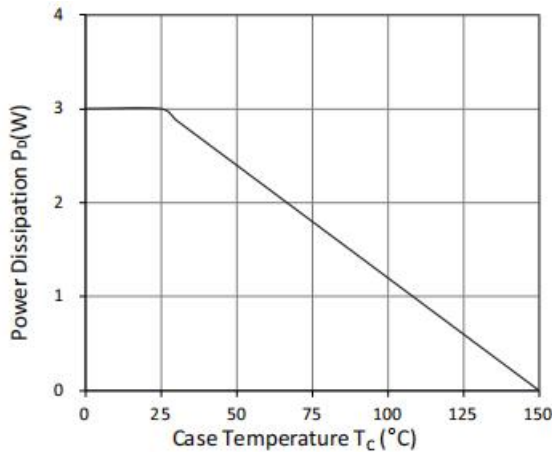


Figure 7: Power Rating Curve

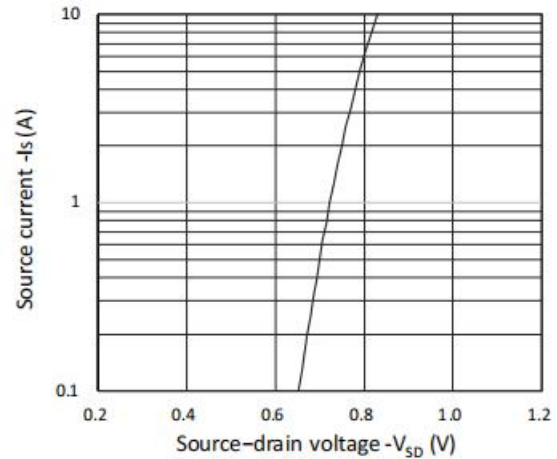


Figure 8: Diode Characteristics

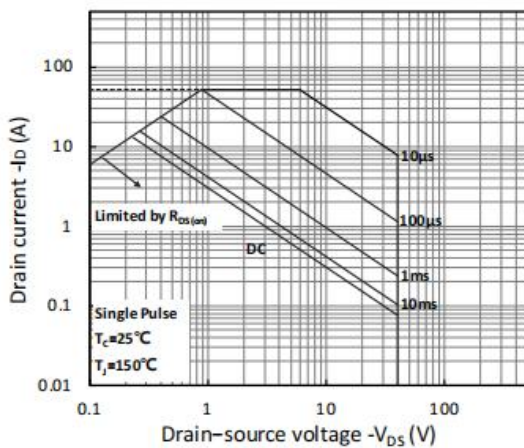


Figure 9: Safe Operating Area

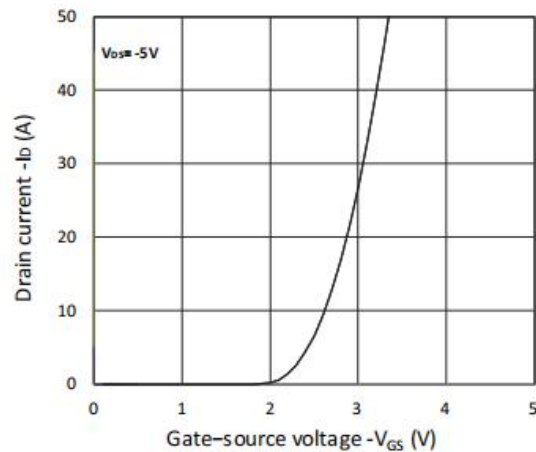


Figure 10: Transfer Characteristics

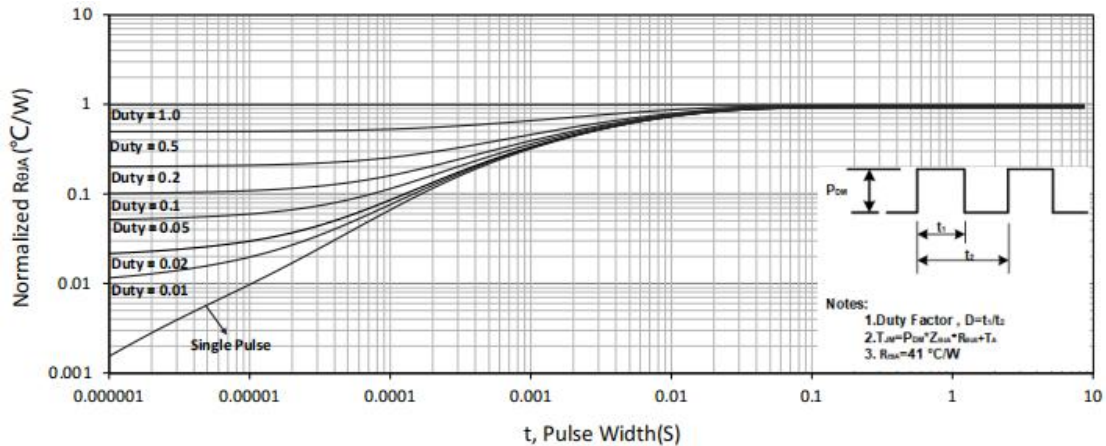
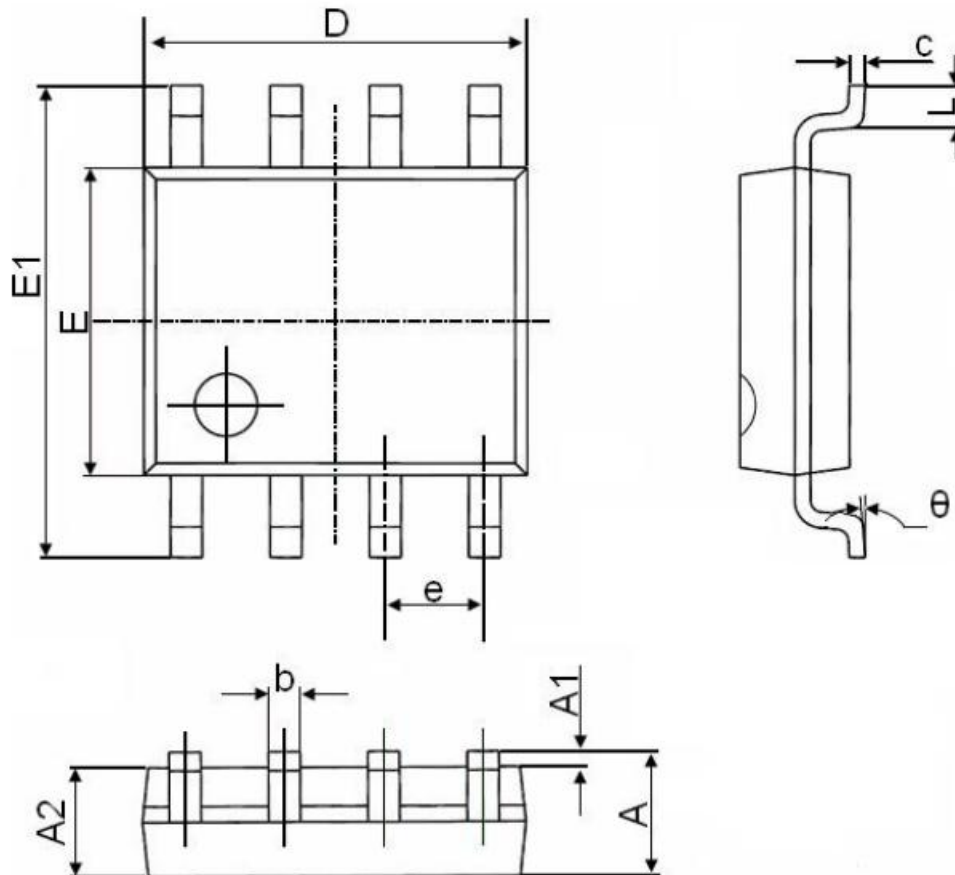


Figure 11: Transient Thermal Response Curve

■ Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°